# R&S®SMA100B RF and Microwave Signal Generator Specifications







# **CONTENTS**

Key features	4
Definitions	5
Introduction	ε
Frequency and platform options (mandatory options)	6
Frequency, high power and rear panel connector options	6
RF characteristics	7
Frequency	7
Reference frequency	7
Level	10
Reverse power	11
VSWR	11
Frequency and level sweep	13
Ramp sweep (R&S®SMAB-B28 option)	13
List mode	13
Spectral purity	14
Analog modulation	22
Simultaneous modulation	22
Amplitude modulation (R&S®SMAB-K720 option)	22
Scan AM (R&S®SMAB-K721 option)	22
Frequency bands for frequency modulation and phase modulation	23
Frequency modulation (R&S®SMAB-K720 option)	24
Phase modulation (R&S®SMAB-K720 option)	24
Pulse modulation (R&S®SMAB-K22 option)	25
VOR modulation (R&S®SMAB-K25 option)	25
ILS modulation (R&S®SMAB-K25 option)	26
Marker beacon (MKR BCN) (R&S®SMAB-K25 option)	26
ADF mode (R&S®SMAB-K25 option)	27
Sources for analog modulation	28
Internal modulation generator	28
Multifunction generator (R&S®SMAB-K24 option)	28
LF frequency sweep	28
LF output	28
Pulse generator (R&S®SMAB-K23 option)	29
Pulse train (R&S®SMAB-K27 option)	29
Pulse generator outputs	29
Additional performance options	30
Differential clock synthesizer (R&S®SMAB-B29 option)	30
R&S®NRP-Z power analysis (R&S®SMAB-K28 option)	35
Pamota control	27

Connectors	38
Front or rear panel connectors	38
Rear panel connectors	38
General data	40
Ordering information	42

# **Key features**

#### First class devices thanks to first class signals

- Purest signals
  - Excellent SSB phase noise in base unit: < -120 dBc (typ.) for 10 GHz at an offset of 20 kHz
  - Outstanding SSB phase noise with option: < -132 dBc (typ.) for 10 GHz at an offset of 10 kHz
  - Lowest close-in SSB phase noise: < -83 dBc (typ.); f = 10 GHz, offset = 10 Hz
  - Virtually no wideband noise: < -160 dBc (typ.) at 10 GHz and an offset of 30 MHz
- Lowest harmonic and nonharmonic signal components
  - Very low harmonic signal components over the entire frequency range (< -63 dBc) even at very high output power
  - Very low nonharmonic signal components of < -90 dBc (typ.) at 10 GHz

#### Very high output power without compromise

- · Exceptionally high output level
  - Ultra high output power up to 38 dBm with the 6 GHz model
  - Over 30 dBm at 18 GHz and 28 dBm at 20 GHz
  - First stage high power upgrade via key code
- · Excellent level accuracy and repeatability for CW signals, narrow pulses and modulated signals

#### User friendly in every detail

- Flexible 2 HU or 3 HU housing
- 3 HU with larger 7" display and multiple front panel connectors
- · Ergonomic operation thanks to state-of-the-art GUI with touch display

### R&S®LegacyPro: refresh your technology

- Plug and play the R&S®SMA100B in an automated test system without changing the test software
- Emulation of R&S®SMA100A, R&S®SMF100A, Keysight PSG, Keysight MXG, etc.

### **Definitions**

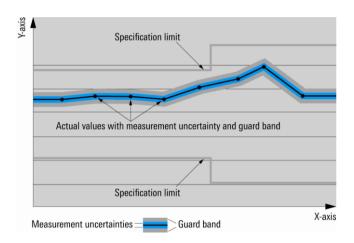
#### General

Product data applies under the following conditions:

- · Three hours storage at ambient temperature followed by 30 minutes warm-up operation
- · Specified environmental conditions met
- · Recommended calibration interval adhered to
- All internal automatic adjustments performed, if applicable

#### Specifications with limits

Represent warranted product performance by means of a range of values for the specified parameter. These specifications are marked with limiting symbols such as  $\langle , \leq , > , \geq , \pm \rangle$ , or descriptions such as maximum, limit of, minimum. Compliance is ensured by testing or is derived from the design. Test limits are narrowed by guard bands to take into account measurement uncertainties, drift and aging, if applicable.



#### Specifications without limits

Represent warranted product performance for the specified parameter. These specifications are not specially marked and represent values with no or negligible deviations from the given value (e.g. dimensions or resolution of a setting parameter). Compliance is ensured by design.

#### Typical data (typ.)

Characterizes product performance by means of representative information for the given parameter. When marked with <, > or as a range, it represents the performance met by approximately 80 % of the instruments at production time. Otherwise, it represents the mean value.

#### Nominal values (nom.)

Characterize product performance by means of a representative value for the given parameter (e.g. nominal impedance). In contrast to typical data, a statistical evaluation does not take place and the parameter is not tested during production.

#### Measured values (meas.)

Characterize expected product performance by means of measurement results gained from individual samples.

#### **Uncertainties**

Represent limits of measurement uncertainty for a given measurand. Uncertainty is defined with a coverage factor of 2 and has been calculated in line with the rules of the Guide to the Expression of Uncertainty in Measurement (GUM), taking into account environmental conditions, aging, wear and tear.

Device settings and GUI parameters are indicated as follows: "parameter: value".

Typical data as well as nominal and measured values are not warranted by Rohde & Schwarz.

In line with the 3GPP/3GPP2 standard, chip rates are specified in Mcps (million chips per second), whereas bit rates and symbol rates are specified in Mbps (million bits per second), kbps (thousand bits per second) or ksps (thousand symbols per second), and sample rates are specified in Msample/s (million samples per second). Mcps, kbps, ksps and Msample/s are not SI units.

### Introduction

### Frequency and platform options (mandatory options)

One of the following frequency options must be installed.

R&S®SMAB-B103	8 kHz to 3 GHz	
R&S®SMAB-B106	8 kHz to 6 GHz	
R&S®SMAB-B112	8 kHz to 12.75 GHz	
R&S®SMAB-B120	8 kHz to 20 GHz	

One of the following platform height options must be selected.

R&S®SMAB-B92	2 HU with 5" touch display
R&S®SMAB-B93	3 HU with 7" touch display

### Frequency, high power and rear panel connector options

The following table shows the frequency options and their corresponding high power, ultra high power and rear panel connector options.

Frequency option	High power option	Ultra high power option	Rear panel connector option
R&S®SMAB-B103	R&S®SMAB-K31	R&S®SMAB-B32	R&S®SMAB-B80
R&S®SMAB-B106	R&S®SMAB-K31	R&S®SMAB-B32	R&S®SMAB-B80
R&S®SMAB-B112	R&S®SMAB-K33	R&S®SMAB-B34	R&S®SMAB-B81
R&S®SMAB-B120	R&S®SMAB-K33	R&S®SMAB-B34	R&S®SMAB-B81

Note: an ultra high power option requires the corresponding high power option to be installed. For example, R&S®SMAB-K31 is a prerequisite for R&S®SMAB-B32.

# **RF** characteristics

Unless stated otherwise, the specifications apply within the specified level range.

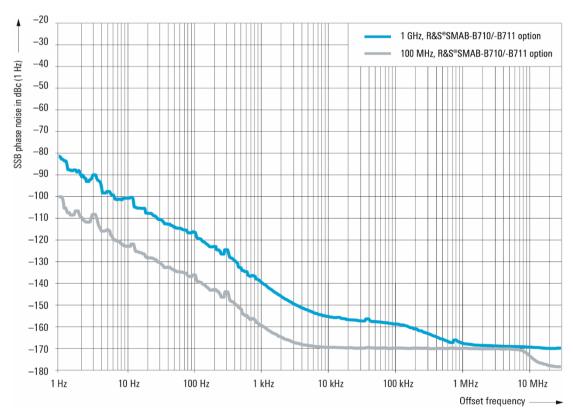
### **Frequency**

Range	R&S®SMAB-B103	8 kHz to 3 GHz	
	R&S®SMAB-B106	8 kHz to 6 GHz	
	R&S®SMAB-B112	8 kHz to 12.75 GHz	
	R&S®SMAB-B120	8 kHz to 20 GHz	
Resolution of setting		0.001 Hz	
Resolution of synthesis	f = 1 GHz	0.053 nHz (nom.)	
Setting time	to within $< 1 \times 10^{-7}$ for f $> 10$ MHz or $< 30$ Hz for f $< 10$ MHz, with GUI update stopped after IEC/IEEE bus delimiter with R&S <sup>®</sup> SMAB-B86 option		
	level setting characteristic: auto	level setting characteristic: auto	
	< 1.5 ms		
	with R&S®SMAB-B711(N) option	< 4.5 ms	
Resolution of phase offset setting		adjustable in 0.01° steps	

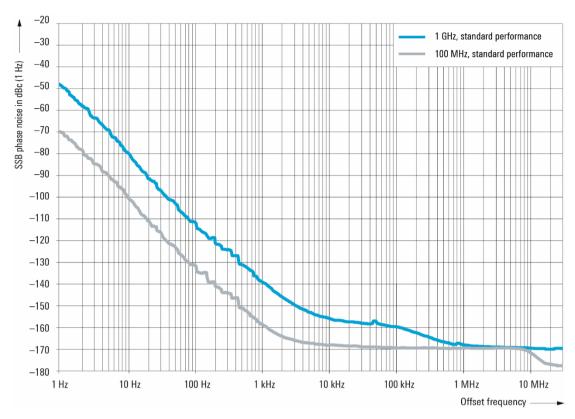
# Reference frequency

Frequency error	at time of calibration in production	
,	standard or with R&S®SMAB-B1H/	< 1 x 10 <sup>-8</sup>
	-B709 options	
	with R&S®SMAB-B710(N)/-B711(N)	< 5 × 10 <sup>-9</sup>
	options	
Aging	after 30 days of uninterrupted operation	
	standard	≤ 1 x 10 <sup>-9</sup> /day
		≤ 1 x 10 <sup>-7</sup> /year
	with R&S®SMAB-B1H/-B709/-B710(N)/	≤ 5 x 10 <sup>-10</sup> /day
	-B711(N) options	≤ 3 × 10 <sup>-8</sup> /year
Temperature effect	in temperature range from 0 °C to +55 °C	
	standard	$\pm 6 \times 10^{-8}$
	with R&S®SMAB-B1H/-B709 option	±6 × 10 <sup>-9</sup>
	with R&S®SMAB-B710(N)/-B711(N)	±3 × 10 <sup>-9</sup>
	options	
Warm-up time	to nominal thermostat temperature	≤ 10 min (nom.)
Input for external reference frequenc	у	
Connector type	REF in on rear panel	BNC female
Input frequency	standard	10 MHz
	with R&S®SMAB-K703 option	10 MHz, 100 MHz
	with R&S®SMAB-K704 option	10 MHz,
		1 MHz to 100 MHz, variable
Input frequency setting resolution	with R&S®SMAB-K704 option	0.1 Hz
Input level range	level limits	0 dBm to 20 dBm
	recommended input level for optimum	7 dBm to 13 dBm
	phase noise performance	
Input impedance		50 Ω (nom.)
Minimum frequency locking range	synchronisation bandwidth: wide	$\pm 3 \times 10^{-6}$
	synchronisation bandwidth: narrow	
	standard or with R&S®SMAB-B1H/	$\pm 0.3 \times 10^{-6}$
	-B709 options	
	with R&S <sup>®</sup> SMAB-B710(N)/-B711(N)	$\pm 0.15 \times 10^{-6}$
	options	
Output for internal reference frequen		
Connector type	REF out on rear panel	BNC female
Output frequency	standard	sine wave 10 MHz
	with R&S®SMAB-K703 option	sine wave 10 MHz, 100 MHz
	with R&S®SMAB-K704 option	T
	instrument set to internal reference	sine wave 10 MHz
	instrument set to external reference	sine wave 10 MHz,
		applied external reference frequency
Output level		7 dBm to 14 dBm
Source impedance		50 Ω (nom.)

Wideband noise	with R&S®SMAB-K703 option, 100 MHz, internal reference, carrier offset = 10 MHz, measurement bandwidth 1 Hz	< -163 dBc, -167 dBc (typ.)
Ultra low noise 1 GHz reference freque	ncy (R&S®SMAB-K703 option)	
Input connector type	1 GHz in on rear panel	SMA female
Input frequency		1 GHz
Input level range	level limits	≥ 6 dBm, ≤ 20 dBm
	recommended input level for optimum	7 dBm to 13 dBm
	phase noise performance	
Input impedance		50 Ω (nom.)
Minimum frequency locking range		±3 x 10 <sup>-6</sup>
Output connector type	1 GHz out on rear panel	SMA female
Output frequency		sine wave 1 GHz
Output level		7 dBm to 13 dBm
Source impedance		50 Ω (nom.)
Wideband noise	1 GHz, internal reference,	< -164 dBc, -168 dBc (typ.)
	carrier offset = 10 MHz,	
	measurement bandwidth 1 Hz	
Input for electronic tuning of internal re	eference frequency	
Connector type	external tune on rear panel	BNC female
Sensitivity	external tuning slope, low	$1 \times 10^{-8}$ /V (typ.)
	external tuning slope, high	$5 \times 10^{-8}$ /V (typ.)
Input voltage range		-10 V to +10 V
Input impedance		10 kΩ (nom.)



Measured SSB phase noise of reference outputs at f = 100 MHz and 1 GHz with the R&S $^{\circ}$ SMAB-B710(N) and R&S $^{\circ}$ SMAB-B711(N) options (only available with the R&S $^{\circ}$ SMAB-K703 option)



Measured SSB phase noise of reference outputs at f = 100 MHz and 1 GHz with the R&S $^{\otimes}$ SMAB-K703 option

#### Reference frequency option concept

		Without option	With R&S®SMAB-K703 option, 1 GHz reference	With R&S®SMAB-K704 option, variable reference input
	10 MHz input frequency	•	•	•
5	100 MHz input frequency	-	•	•
₽ B	1 MHz to 100 MHz input frequency	_	_	•
_	1 GHz input frequency	_	•	_
⊢	10 MHz output frequency	•	•	•
P	100 MHz output frequency	_	•	_
5	"Loop through" of input to output	_	•	•
0	1 GHz output frequency	_	•	_

#### R&S®SMAB-K703 option (1 GHz reference)

When this option is installed, the user can use the 1 GHz low noise input and output for synchronization.

In WIDE mode, the signal generator will use this signal directly as a reference for the synthesizer.

This option should be used if a very high phase stability between multiple generators is required.

The 100 MHz low noise input and output mode is only available with this option.

#### R&S®SMAB-K704 option (variable reference input)

When this option is installed, the user can set the reference input frequency in 0.1 Hz steps between 1.0 MHz and 100 MHz. The signal generator will lock its internal reference oscillator on the input frequency.

#### Note on choosing the proper reference synchronization bandwidth

The user has the choice to set the synchronization bandwidth either to NARROW or WIDE.

In WIDE mode, the best possible phase stability is achieved.

The phase noise performance close to the carrier depends on the phase noise of the external signal source.

In NARROW mode, the reference PLL acts as a clean-up-loop in which the phase noise is mainly determined by the signal generator's internal reference source.

This mode is recommended when using external reference sources with close-to-carrier phase noise worse than the R&S®SMA100B (i. e. rubidium standards).

Please note that due to the slow synchronization, reference locking can take up to 10 seconds.

### Level

Setting range			
R&S®SMAB-B103/-B106	standard	-145 dBm to +20 dBm	
	with R&S®SMAB-K31 option		
	f ≤ 1 MHz	-145 dBm to +30 dBm	
	f > 1 MHz	-145 dBm to +35 dBm	
	with R&S®SMAB-B32 option		
	f ≤ 1 MHz	-145 dBm to +30 dBm	
	f > 1 MHz	-145 dBm to +40 dBm	
R&S®SMAB-B112/-B120	standard		
	f ≤ 13 GHz	-145 dBm to +19 dBm	
	f > 13 GHz	-145 dBm to +18 dBm	
	with R&S®SMAB-K33 option		
	f ≤ 1 MHz	-145 dBm to +30 dBm	
	f > 1 MHz	-145 dBm to +35 dBm	
	with R&S®SMAB-B34 option	Tio abilitio roo abili	
	f ≤ 1 MHz	-145 dBm to +30 dBm	
	f > 1 MHz	-145 dBm to +40 dBm	
Setting resolution	1 > 1 1011 12	0.01 dB	
Specified level range	peak envelope power (PEP)	0.01 db	
R&S®SMAB-B103/-B106	standard		
R&S*SIVIAD-D103/-D100		00 dD to 10 dD	
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	1 MHz < f ≤ 6 GHz	-127 dBm to +19 dBm	
	with R&S®SMAB-K31 option		
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	1 MHz < f ≤ 6 GHz	-127 dBm to +25 dBm	
	with R&S®SMAB-K31 and R&S®SMAB-B32 options		
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	1 MHz < f ≤ 8 MHz	-127 dBm to +25 dBm	
	8 MHz < f ≤ 6 GHz	-127 dBm to +30 dBm	
R&S <sup>®</sup> SMAB-B112/-B120	standard		
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	1 MHz < f ≤ 6 GHz	-127 dBm to +18 dBm	
	6 GHz < f ≤ 13 GHz	-120 dBm to +18 dBm	
	13 GHz < f ≤ 20 GHz	-120 dBm to +17 dBm	
	with R&S®SMAB-K33 option		
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	1 MHz < f ≤ 6 GHz	-127 dBm to +23 dBm	
	6 GHz < f ≤ 20 GHz	-120 dBm to +20 dBm <sup>1</sup>	
	with R&S®SMAB-K33 and R&S®SM		
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	1 MHz < f ≤ 8 MHz	-127 dBm to +25 dBm	
	8 MHz < f ≤ 6 GHz	-127 dBm to +28 dBm	
	6 GHz < f ≤ 18 GHz	-120 dBm to +27 dBm <sup>1</sup>	
	18 GHz < f ≤ 20 GHz	-120 dBm to +24 dBm <sup>1</sup>	

 $<sup>^{1}</sup>$  With the R&S<sup>®</sup>SMAB-B81 rear panel connectors option, the level is reduced by (0.2 dB + 0.025 dB/GHz).

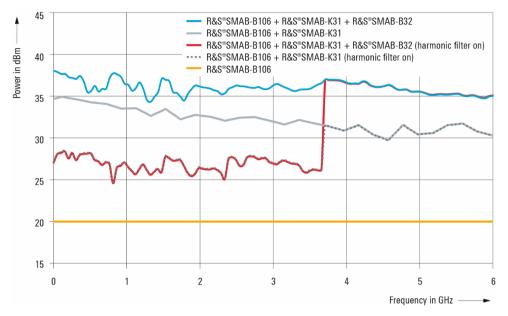
Level accuracy	CW, level setting characteristic: auto, temperature range from +18 °C to +33 °C		
	level from-90 dBm to +25 dBm	level from-90 dBm to +25 dBm	
	8 kHz < f ≤ 8 MHz	< 1.0 dB	
	8 MHz < f ≤ 3 GHz	< 0.5 dB	
	3 GHz < f ≤ 20 GHz	< 0.9 dB	
	level > +25 dBm		
	8 MHz < f ≤ 18 GHz	< 1.0 dB	
	level ≤ -90 dBm		
	100 kHz < f ≤ 8 MHz	< 1.2 dB	
	8 MHz < f ≤ 3 GHz	< 0.8 dB	
	3 GHz < f ≤ 20 GHz	< 1.2 dB	
Additional level error	ALC state off (table)	< 0.7 dB	
Interruption-free level setting range	level setting characteristic:	> 20 dB	
	uninterrupted level setting		
	with R&S®SMAB-K724 option,	> 60 dB, 70 dB (typ.)	
	52 MHz < f ≤ 20 GHz,		
	level setting characteristic: high dynamic		
	uninterrupted		
Setting time	level deviation < 0.1 dB from final value, wi	th GUI update stopped, temperature range	
	from +18 °C to +33 °C, after IEC/IEEE bus	delimiter with R&S®SMAB-B86 option	
	level setting characteristic: auto	< 1.5 ms	
Level setting characteristics	predefined modes to optimize the	• auto	
-	instrument behavior for common	<ul> <li>uninterrupted level setting</li> </ul>	
	applications	strictly monotone	
		constant VSWR	
Automatic level control modes		auto, on, off (table), table and on	

# **Reverse power**

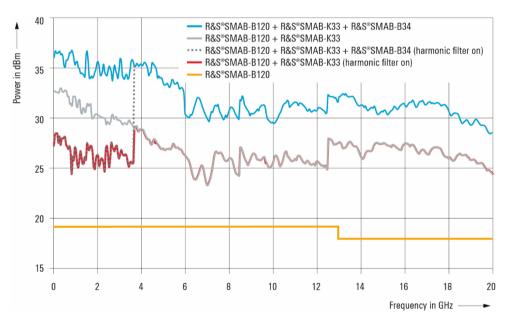
•		
Reverse power	R&S <sup>®</sup> SMAB-B103/-B106, from 50 $\Omega$ source, maximum permissible RF power in output frequency range of RF path for f > 1 MH	
	in case of too high reverse power, the RF output is switched off by a mechanical relay	
	1 MHz < f ≤ 3 GHz 50 W	
	3 GHz < f < 6 GHz	10 W
	R&S®SMAB-B112/-B120,	0.5 W
	from 50 Ω source	
Maximum permissible DC voltage	R&S®SMAB-B103/-B106	50 V
	R&S®SMAB-B112/-B120	5 V

# **VSWR**

Output impedance VSWR in 50 $\Omega$ system,	R&S®SMAB-B103/-B106	
ALC state auto	200 kHz < f ≤ 6 GHz	< 1.6
	R&S <sup>®</sup> SMAB-B112/-B120	
	200 kHz < f ≤ 3 GHz	< 1.9 (meas.)
	3 GHz < f ≤ 6 GHz	< 1.7 (meas.)
	6 GHz < f ≤ 20 GHz	< 1.6 (meas.)
	R&S®SMAB-B112/-B120 with R&S®SMAB-B	B34
	200 kHz < f ≤ 3 GHz < 1.9 (meas.)	
	3 GHz < f ≤ 6 GHz	< 1.7 (meas.)
	6 GHz < f ≤ 20 GHz	< 1.8 (meas.)



Measured maximum available output power versus frequency



Measured maximum available output power versus frequency

# Frequency and level sweep

Operating mode		digital sweep in discrete steps
Sweep parameters		RF frequency or RF level
Trigger modes	execute sweep continuously with internal trigger source	auto
	execute one full sweep	single
	execute one step	step
	sweep start and stop controlled by external trigger signal	start/stop
Trigger source		external trigger signal (INST TRIG at rear), rotary knob, touch panel, remote control
Sweep range		full specified frequency and level range
	interruption-free level sweep with attenuator mode fixed	0.01 dB to 20 dB
	high dynamic uninterrupted level sweep with R&S®SMAB-K724 option, 52 MHz < f ≤ 20 GHz	0.01 dB to 60 dB, 70 dB (typ.)
Sweep shape		sawtooth, triangle
Step size setting resolution	frequency sweep linear	0.001 Hz
	frequency sweep logarithmic	0.01 %
	level sweep	0.01 dB
Dwell time setting range	RF level sweep	3 ms to 100 s
	RF frequency sweep	3 ms to 100 s
	with R&S®SMAB-B711(N) option	5 ms to 100 s
Dwell time setting resolution		0.1 ms

# Ramp sweep (R&S®SMAB-B28 option)

Ramp sweep operation is available in the frequency range 8 MHz < f  $\leq$  f<sub>max</sub>.

Operating mode		synthesized frequency sweep
Trigger modes	execute sweep continuously	auto
	execute one full sweep	single
Trigger source		external trigger signal (INST TRIG at rear),
		rotary knob, touchpanel, remote control
Sweep span range		Ramp sweep frequency range
Maximum sweep rate	f ≤ 375 MHz	500 MHz/ms
	375 MHz < f ≤ 750 MHz	31.25 MHz/ms
	750 MHz < f ≤ 1500 MHz	62.5 MHz/ms
	1.5 GHz < f ≤ 3 GHz	125 MHz/ms
	3 GHz < f ≤ 6 GHz	250 MHz/ms
	6 GHz < f ≤ 12 GHz	500 MHz/ms
	12 GHz < f ≤ 20 GHz	1 GHz/ms
Frequency accuracy		(0.005 % of span)/(sweep time/s)
Sweep time		
Setting range		10 ms to 100 s
Setting resolution		0.1 ms
Frequency markers	number of frequency markers	10

### List mode

Frequency and level values can be stored in a list and triggered by an internal timer or an external trigger.

Run mode		live
Operating modes	internal trigger, infinite	auto
	internal trigger, one sweep per trigger	single
	event	
	internal trigger, one step per trigger event	step
	external trigger, one sweep per trigger	extern single
	event	
	external trigger, one step per trigger event	extern step
Dwell time setting range	can be set individually for each step	1 ms to 100 s
Dwell time setting resolution		0.1 ms

# **Spectral purity**

Harmonics <sup>2</sup>	CW				
	R&S®SMAB-B103/-B106: level = 10	dBm;			
	for instruments equipped with R&S®	SMAB-K31 high power option: level = 10 dBm;			
	for instruments equipped with R&S®	for instruments equipped with R&S®SMAB-B32 ultra high power option: level = 18 dBm			
	100 kHz ≤ f ≤ 10 MHz	< -30 dBc			
	10 MHz ≤ f ≤ 6 GHz	< -60 dBc			
	R&S®SMAB-B112/-B120: level = 10	dBm;			
	for instruments equipped with R&S®	SMAB-K33 high power option: level = 10 dBm;			
	for instruments equipped with R&S®	SMAB-B34 ultra high power option: level = 16 dBm			
	100 kHz ≤ f ≤ 10 MHz	< –30 dBc			
	10 MHz ≤ f ≤ 20 GHz	< -55 dBc			
Nonharmonics	CW, offset > 10 kHz from carrier, lev				
	f ≤ 750 MHz	< -96 dBc			
	750 MHz < f ≤ 1.5 GHz	< -92 dBc			
	1.5 GHz < f ≤ 3 GHz	< –86 dBc			
	3 GHz < f ≤ 6 GHz	< -80 dBc			
	6 GHz < f ≤ 12 GHz	<-74 dBc			
	12 GHz < f ≤ 20 GHz	< -68 dBc			
		SMAB-B711(N) ultra low phase noise option:			
	CW, offset > 10 kHz from carrier, lev				
	f ≤ 1.5 GHz	< -100 dBc			
	1.5 GHz < f ≤ 3 GHz	< -94 dBc			
	3 GHz < f ≤ 6 GHz	< –88 dBc			
	6 GHz < f ≤ 12 GHz	< –82 dBc			
	12 GHz < f ≤ 20 GHz	< –76 dBc			
Subharmonics <sup>3</sup>	CW, level operating mode: auto, level				
Subilamionics	f ≤ 5 GHz	er = 10 dbm < -85 dBc,			
	T ≤ 5 GHZ	< -05 dBc, < -95 dBc with R&S®SMAB-B711(N)			
		` ,			
	5 GHz < f ≤ 20 GHz	option < -60 dBc			
Midahand naiga					
Wideband noise		0 dBm, measurement bandwidth 1 Hz, CW			
		carrier frequency, whichever is lower			
	f ≤ 8 MHz	< -150 dBc			
	8 MHz < f ≤ 1.5 GHz	< –155 dBc			
	1.5 GHz < f ≤ 3 GHz	< –153 dBc			
	3 GHz < f ≤ 6.0 GHz < −150 dBc				
	carrier offset 30 MHz				
	6.0 GHz < f ≤ 12 GHz	< –150 dBc			
	12 GHz < f ≤ 20 GHz	< -145 dBc			
		AB-B711(N) ultra low phase noise option			
	carrier offset 10 MHz or 10 % of	carrier frequency, whichever is lower			
	f ≤ 8 MHz	< -150 dBc			
	8 MHz < f ≤ 1.5 GHz	< -157 dBc			
	1.5 GHz < f ≤ 3 GHz	< -155 dBc			
	3 GHz < f ≤ 6.0 GHz	< -155 dBc			
	carrier offset 30 MHz				
	6.0 GHz < f ≤ 12 GHz	< -154 dBc			
	12 GHz < f ≤ 16 GHz	< -152 dBc			
	carrier offset 100 MHz				
	16 GHz < f ≤ 20 GHz	< -152 dBc			
SSB phase noise	CW, standard performance, carrier offset 20 kHz CW, measurement bandwidth 1 Hz, level = 10 dBm				
SSB phase noise	level = 10 dBm	,			
SSB phase noise	-	< –158 dBc, –165 dBc (typ.)			
SSB phase noise	level = 10 dBm	< -158 dBc, -165 dBc (typ.)			
SSB phase noise	level = 10 dBm f = 10 MHz f = 100 MHz	< -158 dBc, -165 dBc (typ.) < -154 dBc, -159 dBc (typ.)			
SSB phase noise	level = 10 dBm f = 10 MHz f = 100 MHz f = 1 GHz	< -158 dBc, -165 dBc (typ.) < -154 dBc, -159 dBc (typ.) < -135 dBc, -140 dBc (typ.)			
SSB phase noise	level = 10 dBm f = 10 MHz f = 100 MHz f = 1 GHz f = 2 GHz	< -158 dBc, -165 dBc (typ.) < -154 dBc, -159 dBc (typ.) < -135 dBc, -140 dBc (typ.) < -129 dBc, -134 dBc (typ.)			
SSB phase noise	level = 10 dBm f = 10 MHz f = 100 MHz f = 1 GHz f = 2 GHz f = 3 GHz	< -158 dBc, -165 dBc (typ.) < -154 dBc, -159 dBc (typ.) < -135 dBc, -140 dBc (typ.) < -129 dBc, -134 dBc (typ.) < -125 dBc, -130 dBc (typ.)			
SSB phase noise	level = 10 dBm f = 10 MHz f = 100 MHz f = 1 GHz f = 2 GHz f = 3 GHz f = 4 GHz	< -158 dBc, -165 dBc (typ.) < -154 dBc, -159 dBc (typ.) < -135 dBc, -140 dBc (typ.) < -129 dBc, -134 dBc (typ.) < -125 dBc, -130 dBc (typ.) < -123 dBc, -128 dBc (typ.)			
SSB phase noise	level = 10 dBm f = 10 MHz f = 100 MHz f = 1 GHz f = 2 GHz f = 3 GHz	< -158 dBc, -165 dBc (typ.) < -154 dBc, -159 dBc (typ.) < -135 dBc, -140 dBc (typ.) < -129 dBc, -134 dBc (typ.) < -125 dBc, -130 dBc (typ.)			

 $<sup>^{2}\,\,</sup>$  Specifications are not valid for harmonics beyond "specified frequency range".

<sup>&</sup>lt;sup>3</sup> Specifications are not valid for subharmonics beyond "specified frequency range".

### SSB phase noise with R&S®SMAB-B709 option

Specified values in plain text, measured values in brackets () and italics.

SSB phase noise in dBc (1 Hz) , CW, level = 10 dBm					
Offset frequency	1 Hz	10 Hz	100 Hz	1 kHz	
Carrier frequency					
f = 10 MHz	(-98)	-120	-136	-147	
f = 100 MHz	(-79)	-103	-124	-144	
f = 1 GHz	(–59)	-83	-104	-124	
f = 2 GHz	(–53)	<b>-77</b>	-98	-118	
f = 3 GHz	(-49)	-73	-94	-114	
f = 4 GHz	(-47)	<b>-71</b>	<b>-92</b>	-112	
f = 6 GHz	(-43)	<del>-67</del>	-88	-108	
f = 10 GHz	(-39)	-63	-84	-104	
f = 20 GHz	(-33)	<b>–</b> 58	-78	-98	

SSB phase noise in dBc	SSB phase noise in dBc (1 Hz) , CW, level = 10 dBm				
Offset frequency	10 kHz	100 kHz	1 MHz	10 MHz	
Carrier frequency		100	101		
f = 10 MHz	<b>–157</b>	<b>–160</b>	<b>–161</b>		
f = 100 MHz	<b>–155</b>	<b>–155</b>	-162	<b>–162</b>	
f = 1 GHz	-140	-138	<b>–145</b>	-160	
f = 2 GHz	-134	-132	-139	-159	
f = 3 GHz	-130	-128	-136	-159	
f = 4 GHz	-128	-126	-133	<b>–157</b>	
f = 6 GHz	-124	-122	-131	-156	
f = 10 GHz	-120	-118	-124	-148	
f = 20 GHz	-114	-112	-118	-142	

### SSB phase noise with R&S®SMAB-B710(N) option

Specified values in plain text, typical values in brackets (), measured values in brackets () and italics. Specifications above 3 GHz only applicable for R&S®SMAB-B710 option.

SSB phase noise in dBc (1 Hz), CW, level = 10 dBm				
Offset frequency	1 Hz	10 Hz	100 Hz	1 kHz
Carrier frequency				
f = 10 MHz	(-116)	-124 (-132)	-136 (-142)	-147 (-155)
f = 100 MHz	(-96)	-117 (-122)	-129 (-136)	-144 (-150)
f = 1 GHz	(-76)	-97 (-103)	-111 (-116)	-131 (-138)
f = 2 GHz	(-70)	<b>-91</b> ( <b>-97</b> )	-105 (-110)	-125 (-131)
f = 3 GHz	(-66)	-87 (-93)	-101 (-106)	-121 (-128)
f = 4 GHz	(-64)	-86 (-90)	-99 (-104)	-119 (-125)
f = 6 GHz	(-60)	-81 (-87)	-95 ( <b>-</b> 100)	-115 (-122)
f = 10 GHz	(–56)	-77 ( <del>-</del> 82)	-91 (-96)	-111 (-118)
f = 20 GHz	(-50)	-71 ( <del>-</del> 76)	-85 ( <del>-</del> 90)	-105 (-112)

SSB phase noise in dBc (1 Hz) , CW, level = 10 dBm				
Offset frequency	10 kHz	100 kHz	1 MHz	10 MHz
Carrier frequency				
f = 10 MHz	-157 (-164)	-160 (-165)	-161 (-166)	
f = 100 MHz	-155 (-160)	-155 (-160)	-162 (-166)	-162 (-168)
f = 1 GHz	-140 (-145)	-138 (-143)	-145 ( <del>-</del> 151)	-160 (-165)
f = 2 GHz	-134 (-139)	-132 (-137)	-139 (-145)	-159 (-165)
f = 3 GHz	-130 (-135)	-128 (-133)	-136 (-143)	-159 (-164)
f = 4 GHz	-128 (-133)	-126 (-131)	-133 (-139)	-157 (-161)
f = 6 GHz	-124 (-129)	-122 (-128)	-131 (-137)	-156 (-160)
f = 10 GHz	-120 (-125)	-118 (-123)	-124 (-130)	-148 (-153)
f = 20 GHz	-114 ( <del>-</del> 119)	-112 (-117)	-118 (-124)	-142 (-147)

### SSB phase noise with R&S®SMAB-B711(N) option

Specified values in plain text, typical values in brackets ( ), measured values in brackets ( ) and italics. Specifications above 3 GHz only applicable for R&S $^{\otimes}$ SMAB-B711 option.

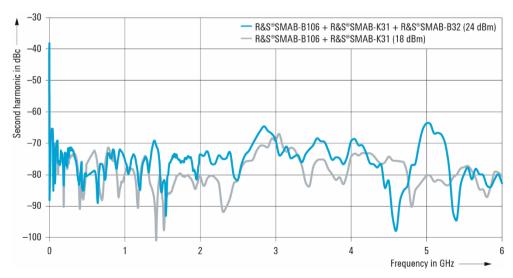
SSB phase noise in dBc (1 Hz) , CW, level = 10 dBm				
Offset frequency	1 Hz	10 Hz	100 Hz	1 kHz
Carrier frequency	/ 116)	124 ( 122)	126 ( 142)	117 ( 156)
f = 10 MHz	(-116)	-124 (-132)	-136 (-142)	-147 (-156)
f = 100 MHz	(–96)	-117 (-122)	-129 ( <del>-</del> 136)	-146 (-150)
f = 1 GHz	(–76)	<b>-97</b> ( <b>-103</b> )	<b>–111 (–117)</b>	-135 ( <del>-</del> 139)
f = 2 GHz	(-70)	<b>-91</b> ( <b>-97</b> )	-105 (-111)	-129 (-133)
f = 3 GHz	(-66)	-87 (-93)	-101 (-107)	-125 (-130)
f = 4 GHz	(-64)	-86 (-91)	<b>-99</b> ( <b>-105</b> )	-122 (-127)
f = 6 GHz	(-60)	-81 ( <del>-</del> 87)	-95 ( <del>-</del> 101)	-119 (-123)
f = 10 GHz	(-56)	<b>-77</b> ( <b>-83</b> )	-91 (-97)	-115 (-119)
f = 20 GHz	(-50)	-71 ( <del>-</del> 77)	-85 ( <del>-</del> 91)	-109 (-113)

SSB phase noise in dBc (1 Hz) , CW, level = 10 dBm				
Offset frequency	10 kHz	100 kHz	1 MHz	10 MHz
Carrier frequency				
f = 10 MHz	-157 (-164)	-160 (-166)	-161 (-166)	
f = 100 MHz	-155 (-160)	-162 (-166)	-162 (-167)	-162 (-168)
f = 1 GHz	-147 (-152)	-148 (-152)	-157 (-161)	-160 (-165)
f = 2 GHz	-142 (-146)	-142 (-146)	-151 ( <del>-</del> 157)	-159 (-164)
= 3 GHz	-138 (-142)	-138 (-143)	-148 (-156)	-159 (-164)
f = 4 GHz	-135 (-140)	-136 (-140)	-147 (-151)	-157 (-162)
f = 6 GHz	-132 (-136)	-132 (-137)	-144 (-150)	-155 ( <del>-</del> 161)
= 10 GHz	-128 (-132)	-128 (-133)	-140 (-145)	-156 (-160)
f = 20 GHz	-122 (-126)	-122 (-127)	-134 (-139)	-148 (-153)

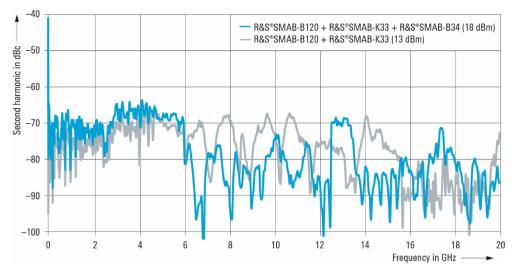
### **RMS** jitter

Specifications above 3 GHz not applicable for R&S®SMAB-B710N and R&S®SMAB-B711N options.

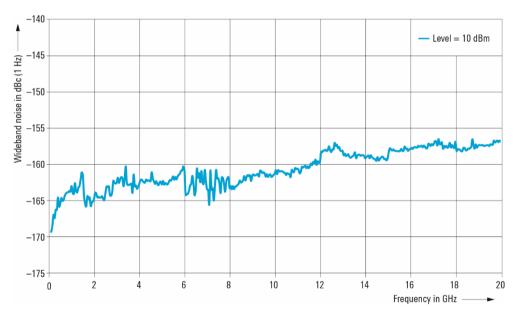
RMS jitter	f = 155 MHz, BW 100 Hz to 1.5 MHz	20.1 fs (meas.)
	f = 622 MHz, BW 1 kHz to 5 MHz	18.7 fs (meas.)
	f = 1 GHz, BW 1 Hz to 10 MHz	558 fs (meas.)
	f = 2.488 GHz, BW 5 kHz to 20 MHz	18.7 fs (meas.)
	f = 9.952 GHz, BW 10 kHz to 80 MHz	18.5 fs (meas.)
With R&S®SMAB-B1H option	f = 155 MHz, BW 100 Hz to 1.5 MHz	19.7 fs (meas.)
	f = 622 MHz, BW 1 kHz to 5 MHz	18.8 fs (meas.)
	f = 1 GHz, BW 1 Hz to 10 MHz	129 fs (meas.)
	f = 2.488 GHz, BW 5 kHz to 20 MHz	18.7 fs (meas.)
	f = 9.952 GHz, BW 10 kHz to 80 MHz	18.5 fs (meas.)
With R&S®SMAB-B709 option	f = 155 MHz, BW 100 Hz to 1.5 MHz	18.5 fs (meas.)
	f = 622 MHz, BW 1 kHz to 5 MHz	13.6 fs (meas.)
	f = 1 GHz, BW 1 Hz to 10 MHz	129 fs (meas.)
	f = 2.488 GHz, BW 5 kHz to 20 MHz	13.6 fs (meas.)
	f = 9.952 GHz, BW 10 kHz to 80 MHz	13.1 fs (meas.)
With R&S®SMAB-B710(N) option	f = 155 MHz, BW 100 Hz to 1.5 MHz	19.7 fs (meas.)
	f = 622 MHz, BW 1 kHz to 5 MHz	18.7 fs (meas.)
	f = 1 GHz, BW 1 Hz to 10 MHz	23.7 fs (meas.)
	f = 2.488 GHz, BW 5 kHz to 20 MHz	18.6 fs (meas.)
	f = 9.952 GHz, BW 10 kHz to 80 MHz	16.6 fs (meas.)
With R&S®SMAB-B711(N) option	f = 155 MHz, BW 100 Hz to 1.5 MHz	8.4 fs (meas.)
	f = 622 MHz, BW 1 kHz to 5 MHz	5.1 fs (meas.)
	f = 1 GHz, BW 1 Hz to 10 MHz	17.5 fs (meas.)
	f = 2.488 GHz, BW 5 kHz to 20 MHz	4.1 fs (meas.)
	f = 9.952 GHz, BW 10 kHz to 80 MHz	3.8 fs (meas.)
Residual FM	RMS values at f = 1 GHz	
	0.3 kHz to 3 kHz, weighted (ITU-T)	< 1 Hz
	0.03 kHz to 23 kHz	< 4 Hz
Residual AM	level = 8 dBm,	< 0.02 %
	RMS value (0.03 kHz to 20 kHz)	



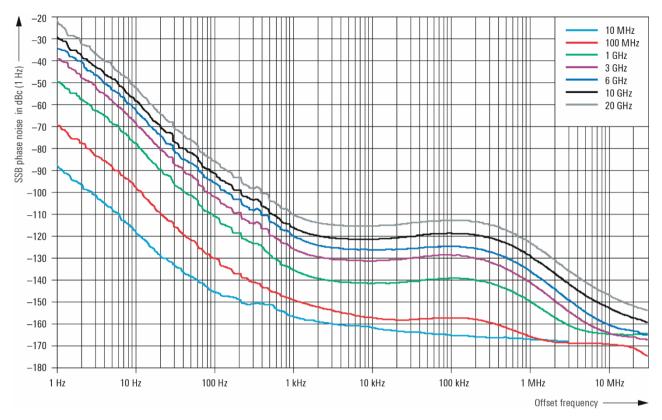
Measured harmonics versus carrier frequency with harmonic filter on for  $f \le 3.7$  GHz



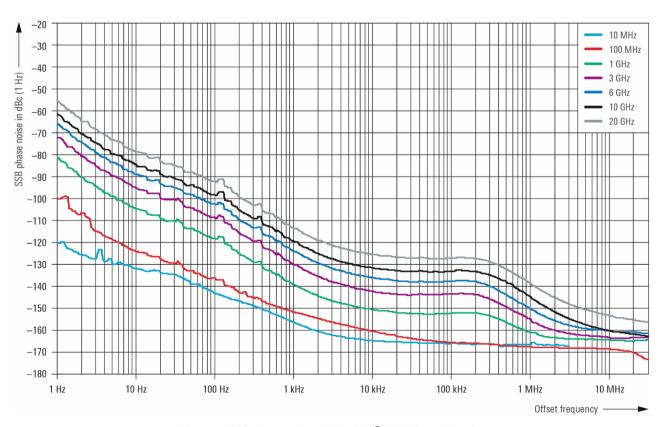
Measured harmonics versus carrier frequency with harmonic filter on for f ≤ 3.7 GHz



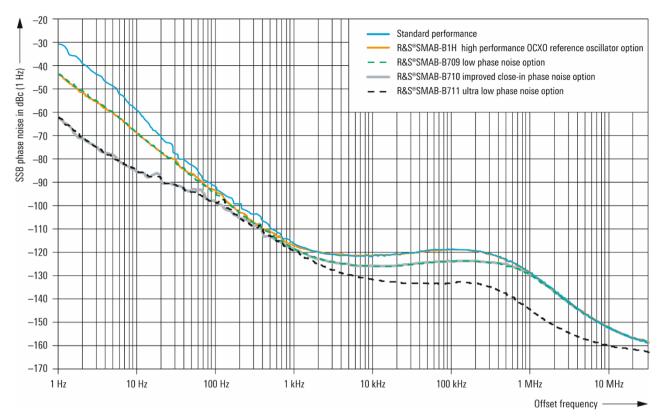
Measured wideband noise at 30 MHz offset and +10 dBm versus carrier frequency with the R&S®SMAB-B120, R&S®SMAB-B711 and R&S®SMAB-B34 options; measured with the R&S®FSWP phase noise analyzer



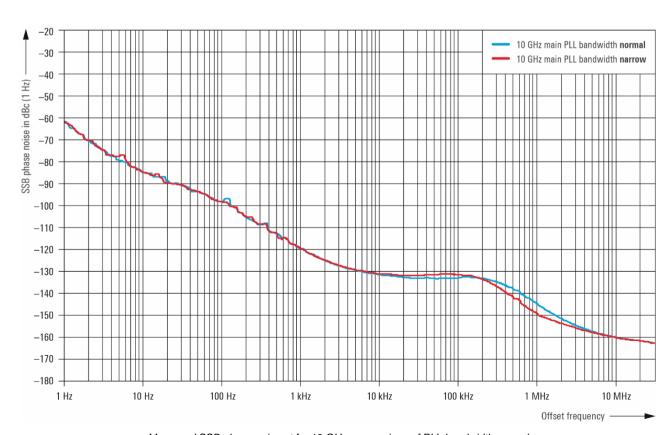
Measured SSB phase noise (standard performance)



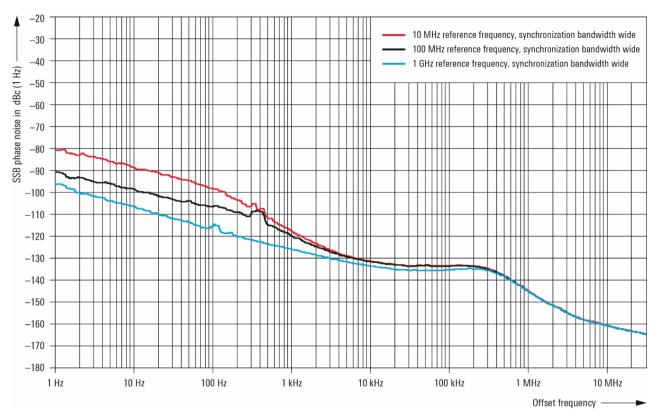
Measured SSB phase noise with the R&S®SMAB-B711(N) option



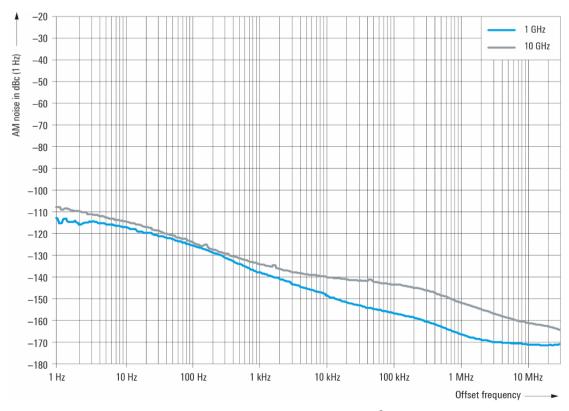
Measured SSB phase noise at f = 10 GHz, standard performance versus the R&S $^{\circ}$ SMAB-B1H, R&S $^{\circ}$ SMAB-B709, R&S $^{\circ}$ SMAB-B710 and R&S $^{\circ}$ SMAB-B711 options



Measured SSB phase noise at f = 10 GHz, comparison of PLL bandwidth normal and narrow with the R&S®SMAB-B711 option



Measured residual SSB phase noise at f = 10 GHz with the R&S®SMAB-B711 option, comparison of different reference frequencies



Measured AM noise at f = 1 GHz and 10 GHz with the R&S®SMAB-B711 option

# **Analog modulation**

### Simultaneous modulation

	Amplitude modulation	Scan AM	Frequency modulation	Phase modulation	Pulse modulation
Amplitude modulation		_	•	•	•
Scan AM	_		•	•	•
Frequency modulation	•	•		_	•
Phase modulation	•	•	_		•
Pulse modulation	•	•	•	•	

 $<sup>\</sup>bullet$  = compatible, - = incompatible,  $\circ$  = compatible with limitations

With certain types of avionics modulation (VOR, ILS, ADF), simultaneous modulation is not possible.

### Amplitude modulation (R&S®SMAB-K720 option)

For f ≥ 100 kHz, attenuator mode: auto, level (PEP) <sup>4</sup> = 10 dBm or level = 15 dBm for instruments equipped with R&S®SMAB-B32/-B34 ultra high power option. At high levels, modulation is clipped when the maximum PEP is reached.

Modulation source		internal, external, internal + external	
External coupling		AC, DC	
AM type		linear, exponential	
Linear AM depth			
Setting range	internal modulation source	0 % to 100 %	
	external modulation source	0 %/V to 100 %/V	
Setting resolution		0.01 %(/V)	
AM depth (m) error	f <sub>mod</sub> = 1 kHz and m < 80 %	< (3 % of reading + 1 %)	
Exponential AM depth			
Setting range	internal modulation source	0 dB to 30 dB	
	external modulation source	0 dB/V to 30 dB/V	
Setting resolution		0.01 dB(/V)	
AM distortion	f <sub>mod</sub> = 1 kHz		
	m = 30 %	< 1 %	
	m = 80 %	< 2 %	
Modulation frequency response	m = 60 %, coupling: DC/AC, input impedance: 50 $\Omega$		
	DC, 10 Hz to 100 kHz	< 3 dB	
Incidental φM at AM	$m = 30 \%$ , $f_{mod} = 1 \text{ kHz}$ , $\pm peak/2$		
·	f ≤ 15 GHz	< 0.15 rad	
	f > 15 GHz	< 0.2 rad	

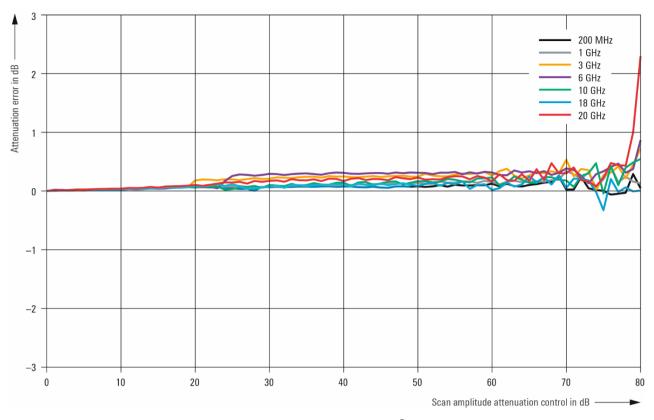
# Scan AM (R&S®SMAB-K721 option)

Level (PEP)  $^4$  = 10 dBm or Level = 15 dBm for instruments equipped with R&S®SMAB-B32/-B34 ultra high power option. Scan AM is available for 52 MHz < f ≤ 20 GHz.

Prerequisite: R&S®SMAB-K720 option must be installed.

Modulation source		internal, external, internal + external
External coupling		DC
Scan AM depth		
Setting range	internal modulation source	0 dB to 100 dB
	external modulation source	0 to 100 dB/V
Resolution of setting		0.01 dB
Maximum attenuation		> 60 dB, 70 dB (typ.)
Attenuation error	level setting characteristic: auto, temperature range from +18 °C to +33 °C	
	0 dB < m ≤ 10 dB	< 0.25 dB
	10 dB < m ≤ 20 dB	< 1 dB
	20 dB < m ≤ 40 dB	< 2 dB (typ.)
	40 dB < m ≤ 50 dB	< 3 dB (typ.)
	50 dB < m ≤ 60 dB	< 4 dB (typ.)
Rise/fall time	transition time: 10 % to 90 % (log) for	< 10 µs (meas.)
	RF amplitude step of 60 dB	

<sup>&</sup>lt;sup>4</sup> PEP = peak envelope power.



Measured Scan AM attenuation error with the R&S®SMAB-K721 option

# Frequency bands for frequency modulation and phase modulation

Multiplier N is used to define FM and  $\phi M$  specifications within this document.

Multiplier (N) for different frequency	FM mode: low noise,		
ranges	φM mode: low noise		
_	f ≤ 8 MHz	1/2	
	8 MHz < f ≤ 11.71875 MHz	1/128	
	11.71875 MHz < f ≤ 23.4375 MHz	1/64	
	23.4375 MHz < f ≤ 46.875 MHz	1/32	
	46.875 MHz < f ≤ 93.75 MHz	1/16	
	93.75 MHz < f ≤ 187.5 MHz	1/8	
	187.5 MHz < f ≤ 375 MHz	1/4	
	375 MHz < f ≤ 750 MHz	1/2	
	750 MHz < f ≤ 1.5 GHz	1	
	1.5 GHz < f ≤ 3 GHz	2	
	3 GHz < f ≤ 6 GHz	4	
	6 GHz < f ≤ 12 GHz	8	
	12 GHz < f ≤ 20 GHz	16	
	FM mode: high bandwidth,		
	φM mode: high bandwidth, high deviation		
	f ≤ 350 MHz	1/2	
	350 MHz < f ≤ 375 MHz	1/4	
	375 MHz < f ≤ 750 MHz	1/2	
	750 MHz < f ≤ 1.5 GHz	1	
	1.5 GHz < f ≤ 3 GHz	2	
	3 GHz < f ≤ 6 GHz	4	
	6 GHz < f ≤ 12 GHz	8	
	12 GHz < f ≤ 20 GHz	16	

# Frequency modulation (R&S®SMAB-K720 option)

Specifications only valid for main PLL bandwidth normal.

Modulation source		internal, external, internal + external	
External coupling		AC, DC	
FM modes		high bandwidth, low noise	
Maximum deviation	FM mode: high bandwidth	N × 10 MHz	
	FM mode: low noise	N × 100 kHz	
Resolution of setting		< 0.02 % of set deviation or N × 0.1 Hz, whichever is greater, min. 0.01 Hz	
FM deviation error	f <sub>mod</sub> = 10 kHz, deviation ≤ half of max. devia	tion or 10 MHz, whichever is lower	
	source: internal	< (1.5 % of reading + 20 Hz)	
	source: external, input impedance: high	< (2 % of reading + 20 Hz)	
FM distortion	$f_{mod} = 10 \text{ kHz}$ , deviation = N × 1 MHz	< 0.1 %	
Modulation frequency response	FM mode: high bandwidth, coupling: DC/AC, input impedance: 50 $\Omega$		
	DC, 10 Hz to 100 kHz	< 0.5 dB	
	f > 350 MHz		
	DC, 10 Hz to 10 MHz	< 3 dB	
	f ≤ 350 MHz		
	DC, 10 Hz to 5 MHz	< 3 dB	
	FM mode: low noise, coupling: DC/AC, inpu	t impedance: 50 Ω	
	DC, 10 Hz to 100 kHz	< 3 dB	
Synchronous AM with FM	FM mode: high bandwidth, 40 kHz deviation, f <sub>mod</sub> = 1 kHz		
	8 MHz < f ≤ 3 GHz	< 0.1 %	
	f > 3 GHz	< 0.2 %	
Carrier frequency offset with FM DC	after FM offset calibration, FM source	< 0.2 % of set deviation	
	external, input impedance 50 Ω		

# Phase modulation (R&S®SMAB-K720 option)

Specifications only valid for main PLL bandwidth normal.

Modulation source		internal, external, internal + external	
External coupling		AC, DC	
φM modes		high deviation, high bandwidth, low noise	
Maximum deviation	φM mode: high deviation	N × 20 rad	
	φM mode: high bandwidth	N x 1 rad	
	φM mode: low noise	N × 0.25 rad	
Resolution of setting	φM modes: high deviation, low noise	< 0.02 % of set deviation or N × 20 µrad,	
		whichever is greater, min. 1 µrad	
	φM mode: high bandwidth	< 0.1 % of set deviation,	
		min. N × 20 μrad	
φM deviation error	f <sub>mod</sub> = 10 kHz, deviation ≤ half of max. devia	tion	
	source: internal	< (1.5 % of reading + 0.003 rad)	
	source: external, input impedance: high	< (2 % of reading + 0.003 rad)	
φM distortion	$f_{mod} = 10 \text{ kHz},$	< 0.2 %, < 0.1 % (typ.)	
	deviation = half of max. deviation		
Modulation frequency response	φM mode: high deviation, coupling: DC/AC, input impedance: 50 Ω		
	deviation ≤ N × 5 rad	< 1 dB	
	DC, 10 Hz to 500 kHz		
	deviation > N x 5 rad	< 1 dB	
	DC, 10 Hz to 10 kHz		
	φM mode: high bandwidth, coupling: DC/AC	C, input impedance: 50 Ω	
	DC, 10 Hz to 100 kHz	< 1 dB	
	f > 350 MHz		
	DC, 10 Hz to 10 MHz	< 3 dB	
	f ≤ 350 MHz		
	DC, 10 Hz to 5 MHz	< 3 dB	
	φM mode: low noise, coupling: DC/AC, input impedance: 50 $Ω$		
	DC, 10 Hz to 100 kHz	< 3 dB	

# Pulse modulation (R&S®SMAB-K22 option)

Modulation source		external	
	with R&S®SMAB-K23 option	external, internal	
On/off ratio		> 80 dB	
Rise/fall time	f > 700 MHz		
	10 % to 90 % of RF amplitude	< 10 ns, 5 ns (typ.)	
Minimum pulse width	f > 700 MHz		
	50 % / 50 % of RF amplitude	< 20 ns	
Pulse repetition frequency		0 Hz to 25 MHz	
Video feedthrough	level < 10 dBm		
	f≤3 GHz	< 10 % of RF	
	f > 3 GHz	< 10 % of RF,	
		< 2 mV (peak-to-peak)	
Pulse overshoot		< 10 %	
Pulse delay	pulse external trigger to RF	50 ns (nom.)	
Pulse external trigger input			
Input impedance		10 kΩ or 50 Ω (nom.)	
Threshold voltage		0 V to 2.0 V (nom.)	
Input polarity		normal, inverse	

# VOR modulation (R&S®SMAB-K25 option)

Attenuator mode AUTO, level (PEP) <sup>5</sup> within specified level range. VOR specification valid for carrier frequency range from 108 MHz to 118 MHz.

VOR operating modes	generation of VOR signal	NORM
	30 Hz VAR tone	VAR
	9.96 kHz carrier, unmodulated	subcarrier
	9.96 kHz carrier, modulated	subcarrier + FM
Modulation tones		
Frequency error	30 Hz (VAR, REF)	< (0.001 Hz + relative deviation of
		reference frequency × 30 Hz)
Frequency setting range	30 Hz REF	10 Hz to 60 Hz
	9.96 kHz FM carrier	5 kHz to 15 kHz
	COM/ID tone	0.1 Hz to 20 kHz
Frequency setting resolution		0.1 Hz
FM deviation setting range	9.96 kHz FM carrier	0 Hz to 960 Hz
FM deviation setting resolution	9.96 kHz FM carrier	1 Hz
FM deviation error	9.96 kHz FM carrier at 480 Hz deviation	< 1 Hz
External AM tone	input connector	Ext 1
Modulation depth		
Sum of modulation depths of 30 Hz (\	/AR) signal, 9.96 kHz FM carrier, COM/ID and ext	ternal AM signal must not exceed 100 %.
AM depth setting range		0 % to 100 %
AM depth setting resolution		0.1 %
AM depth error	30 Hz (VAR, REF), 30 % AM depth	< 0.5 % AM depth
	9.96 kHz FM carrier, 30 % AM depth	< 0.5 % AM depth
	COM/ID, tone = 1020 Hz, depth = 10 %	< 0.5 % AM depth
External AM tone	sensitivity	0.01 V/%
Bearing angle		
Setting range		0° to 360°
- <del>-</del>	default cetting	0.00°
	default setting	0.00
Setting resolution	derauit setting	0.01°

<sup>&</sup>lt;sup>5</sup> PEP = peak envelope power.

# ILS modulation (R&S®SMAB-K25 option)

Attenuator mode AUTO, level (PEP) <sup>6</sup> within specified level range. ILS-LOC specification valid for carrier frequency range from 108 MHz to 118 MHz. ILS-GS specification valid for carrier frequency range from 329 MHz to 335 MHz.

ILS modulation	generation of ILS localizer signal, COM/ID tone possible	ILS-LOC
		ILS-GS
III O an anatica na anatan	generation of ILS glideslope signal	
ILS operating modes	NORM	90 Hz + 150 Hz + COM/ID tone (ILS-LOC)
	90 Hz	suppression of 150 Hz modulation tone
	150 Hz	suppression of 90 Hz modulation tone
ILS modulation tones	. Server de de discontra de la contra del contra de la contra del contra de la contra della cont	and the second of the
. ,	e is varied, the other tone is automatically ch	9 1 1
Frequency error		< (0.02 Hz + relative deviation of reference
_		frequency × ILS tone frequency)
Frequency setting range	90 Hz tone	60 Hz to 120 Hz
	150 Hz tone	100 Hz to 200 Hz
	COM/ID tone	0.1 Hz to 20 kHz
Frequency setting resolution	90 Hz tone	0.3 Hz
	150 Hz tone	0.5 Hz
	COM/ID tone	0.1 Hz
External AM tone	input connector	Ext 1
Modulation depth		
Sum of modulation depths of 90 Hz, 150 Hz	z, COM/ID and external AM signal must not of	exceed 100 %.
Setting range	SDM of 90 Hz, 150 Hz, COM/ID tone	0 % to 100 %
	ILS-LOC default setting	40 %
	ILS-GS default setting	80 %
Setting resolution	SDM and COM/ID depth	0.1 %
AM depth error	SDM = 40 %	< 0.8 % AM depth
	SDM = 80 %	< 1.6 % AM depth
	COM/ID, tone = 1020 Hz, depth = 10 %	< 0.5 % AM depth
External AM tone	sensitivity	0.01 V/%
Difference in depth of modulation (DDM)		
Setting range		0 to ±SDM
Setting resolution		0.0001
Error		< 0.0003 + 2 % of set DDM
ILS phase		
Setting range		0° to 120°
Setting resolution		0.01°
Error		< 0.05°

# Marker beacon (MKR BCN) (R&S®SMAB-K25 option)

Attenuator mode AUTO, level (PEP) within specified level range.

MKR-BCN specification valid for carrier frequency range from 74 MHz to 76 MHz.

Marker beacon modulation tones		
Frequency error		< (0.001 Hz + relative deviation of reference frequency × marker frequency)
Marker frequencies		400 Hz, 1300 Hz and 3000 Hz
COM/ID tone frequency setting range		0.1 Hz to 20 kHz
COM/ID tone frequency setting resolution		0.1 Hz
Marker beacon modulation depth		
Sum of modulation depths of marker tone	and COM/ID signal must not exceed 1	00 %.
AM depth setting range		0 % to 100 %
	marker tone default setting	95 %
AM depth setting resolution		0.1 %
AM depth error	marker tone	< 4 % AM depth
	COM/ID, tone = 1020 Hz	< 0.5 % AM depth

<sup>&</sup>lt;sup>6</sup> PEP = peak envelope power.

# ADF mode (R&S®SMAB-K25 option)

The ADF mode provides a carrier frequency of 190 kHz with 30 % AM depth at 1 kHz modulation rate.

Frequency error	ADF tone	< (0.001 Hz + relative deviation of	
		reference frequency × ADF frequency)	
ADF frequency setting range		0.1 Hz to 20 kHz	
ADF setting resolution		0.1 Hz	
AM depth setting range		0 % to 100 %	
AM depth setting resolution		0.1 %	
	ADF tone default setting	30 %	

# Sources for analog modulation

# Internal modulation generator

Signal types		sine
Frequency setting range		0.1 Hz to 1 MHz
Frequency setting resolution		0.01 Hz
Frequency error		< (0.001 Hz + relative deviation of reference frequency × modulation
		frequency)
Frequency response	up to 1 MHz	< 0.3 dB
Distortion	f < 100 kHz, at $R_1 \ge 50 \Omega$ , level ( $V_{EME}$ ) < 1 V	< 0.1 %

# Multifunction generator (R&S®SMAB-K24 option)

Signal types	LF generator 1	sine, pulse, triangle, trapezoid
	LF generator 2	sine, pulse, triangle, trapezoid
	noise generator	Gaussian, equal
	(noise amplitude distribution)	
Frequency range	sine	0.1 Hz to 10 MHz
	pulse, triangle, trapezoid	0.01 Hz to 1 MHz (displayed value)
	noise bandwidth	100 kHz to 10 MHz
Resolution of setting	sine	0.01 Hz
-	pulse, triangle, trapezoid	10 ns
	noise bandwidth	100 kHz
Frequency error		< (0.001 Hz + relative deviation of
		reference frequency × modulation
		frequency)
Frequency response	sine, up to 1 MHz	< 0.3 dB
	sine, up to 10 MHz	< 1 dB
Distortion	f < 100 kHz,	< 0.1 %
	at R <sub>L</sub> ≥ 50 Ω, level (V <sub>EMF</sub> ) 1 V	

# LF frequency sweep

Operating mode		digital sweep in discrete steps
Trigger modes	execute sweep continuously with internal trigger source	auto
	execute one full sweep	single
	execute one step	step
	sweep start and stop controlled by external trigger signal	start/stop
Trigger source		external trigger signal (INST TRIG at rear),
		rotary knob, touch panel, remote control
Sweep range		full frequency range
Sweep shape		sawtooth, triangle
Step size	linear	full frequency range
	logarithmic	0.01 % to 100 % per step
Dwell time setting range	-	3 ms to 100 s
Dwell time setting resolution		0.1 ms

# LF output

Monitoring of resulting modulation signal		AM, FM , φM
for		
Source		LF generator 1, LF generator 2, noise
		generator, external 1, external 2
Output voltage	V <sub>peak</sub> at LF connector,	
	open-circuit voltage EMF	
Setting range		1 mV to 4 V
Setting resolution		1 mV
Setting error	$f = 1 \text{ kHz}, R_L > 50 \text{ k}\Omega$	< (1 % of reading + 1 mV)
Output impedance		50 Ω (nom.)

# Pulse generator (R&S®SMAB-K23 option)

Pulse modes		single pulse, double pulse	
Trigger modes	free run, internally triggered	auto	
		external trigger	
		external gate	
Pulse period			
Setting range		20 ns to 100 s	
Setting resolution		5 ns	
Pulse width	pulse widths of double pulses can b	e set independently	
Setting range		5 ns to 100 s	
Setting resolution		5 ns	
Pulse delay			
Setting range		0 s to 100 s	
Setting resolution		5 ns	
Double-pulse spacing			
Setting range		10 ns to 100 s	
Setting resolution		5 ns	
External trigger			
Delay	trigger to video output	40 ns (nom.)	
Jitter		< 5 ns (nom.)	

# Pulse train (R&S®SMAB-K27 option)

The R&S®SMAB-K27 option extends the functionality of the pulse generator (R&S®SMAB-K23 option). With this option, pulses and sequences of pulses can be user-defined in order to generate jittered or staggered pulse scenarios widely used in radar applications.

Prerequisite: R&S®SMAB-K23 option must be installed.

Pulse mode	user-settable pulse width, pulse spacing and pulse sequences	train
Trigger modes	free run, internally triggered	auto
		external trigger
Number of bursts		1 to 2047
Number of identical pulses per burst		1 to 65535
Pulse on time setting range		0 ns to 5 ms
Pulse off time setting range		5 ns to 5 ms
Pulse on and off time setting resolution		5 ns

### **Pulse generator outputs**

SYNC output	output of a synchronizing pulse a	output of a synchronizing pulse at pulse start or start of pulse sequence	
Connector type	PULSE SYNC output	BNC female	
SYNC output level	R <sub>L</sub> ≥ 50 Ω	digital signal 0 V/3.3 V (nom.)	
SYNC pulse width	pulse period < 100 ns	10 ns (nom.)	
	pulse period ≥ 100 ns	50 ns (nom.)	
	or externally triggered		
VIDEO output	output of pulse generator signal	output of pulse generator signal	
Connector type	PULSE VIDEO output	BNC female	
VIDEO output level	R <sub>L</sub> ≥ 50 Ω	digital signal 0 V/3.3 V (nom.)	

# Additional performance options

# Differential clock synthesizer (R&S®SMAB-B29 option)

The R&S®SMAB-B29 option provides a differential or single-ended clock signal with selectable waveform and DC offset up to 3 GHz or up to 6 GHz with the R&S®SMAB-K722 option.

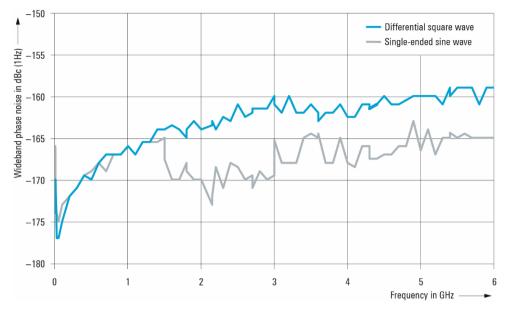
The R&S®SMAB-K722 option is not available for instruments equipped with the 3 GHz R&S®SMAB-B103 RF frequency option. The frequency of the clock synthesizer (R&S®SMAB-B29 option) can be set independently of the RF frequency of the R&S®SMAB100A.

Specifications above 3 GHz are only valid for instruments equipped with the R&S®SMAB-K722 option.

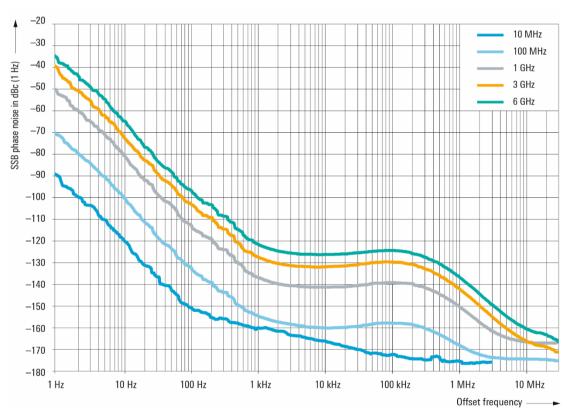
Output types		differential square wave,
Output types		differential sine wave.
		single-ended sine wave,
		differential CMOS
Frequency		
Frequency range	differential square wave,	100 kHz to 3 GHz
	single-ended sine wave	
	differential sine wave	10 MHz to 3 GHz
	with R&S®SMAB-K722 option	10 MHz to 6 GHz
	differential square wave, single-ended	100 kHz to 6 GHz
	sine wave	
	differential sine wave	10 MHz to 6 GHz
	CMOS output	100 kHz to 200 MHz
Resolution of setting	•	0.001 Hz
Resolution of synthesis	f = 1 GHz	0.053 nHz (nom.)
Frequency setting time	to within $<1 \times 10^{-7}$ for f > 10 MHz,	< 1.5 ms
3	with GUI update stopped	
	after IEC/IEEE bus delimiter with	
	R&S®SMAB-B86 option	
Level	•	
Level setting range	sine wave, differential and single-ended	-24 dBm to 20 dBm
	differential square wave	fixed
	differential CMOS	0.8 V to 2.7 V
Output connectors		
Connector type	CLK SYN, CLK SYN_N outputs	SMA female
,.	with R&S®SMAB-B93 option (3 HU)	front panel
	with R&S®SMAB-B92 option (2 HU) or	rear panel
	with R&S®SMAB-B93 option (3 HU) and	
	R&S®SMAB-B80/-B81 rear panel	
	connector options	
Reverse power		
Reverse power (from 50 Ω source)	maximum permissible RF power	0.05 W
Maximum permissible DC voltage	sine wave and square wave, DC offset disabled	±5 V
	any output type with DC offset enabled	0 V (short-circuit-proof)
	differential CMOS	0 V (short-circuit-proof)
DC offset		
Setting range	not available in CMOS mode	–5 V to +5 V
Setting resolution		1 mV
DC offset source impedance		50 Ω (nom.)
Spectral purity		
Nonharmonics	offset > 10 kHz from carrier, level = 10 dBn	n, sine wave
	f ≤ 10 MHz	< –90 dBc
	10 MHz < f ≤ 750 MHz	< -96 dBc
	750 MHz < f ≤ 1.5 GHz	< -92 dBc
	1.5 GHz < f ≤ 3 GHz	< -86 dBc
	3 GHz < f ≤ 6 GHz	< -80 dBc
	instruments equipped with R&S®SMAB-B70	09/-B710(N)/-B711(N)
	f ≤ 1.5 GHz	<-100 dBc
	1.5 GHz < f ≤ 3 GHz	< -94 dBc
	3 GHz < f ≤ 6 GHz	< -88 dBc

30

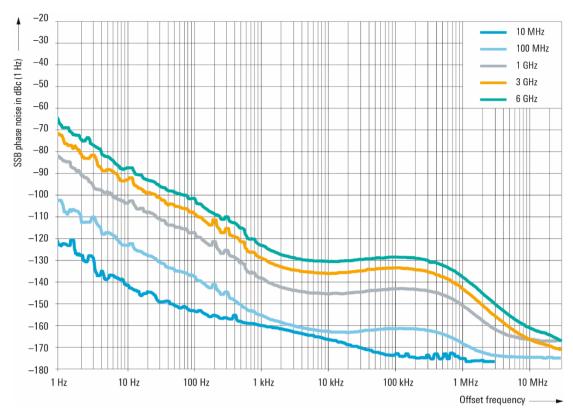
Wideband noise		offset 10 MHz, measurement bandwidth 1 Hz	
	carrier offset 10 MHz or 10 % of carrier frequency, whichever is lower		
	f≤8 MHz	< -150 dBc	
	8 MHz < f ≤ 1.5 GHz	< -155 dBc	
	1.5 GHz < f ≤ 3 GHz	< -153 dBc	
	carrier offset 30 MHz		
	3 GHz < f ≤ 6.0 GHz	< -150 dBc	
	instruments equipped with R&S®SMAB-B	711(N) ultra low phase noise option	
	carrier offset 10 MHz or 10 % of carrie	r frequency, whichever is lower	
	f≤8 MHz	< -150 dBc	
	8 MHz < f ≤ 1.5 GHz	< -157 dBc	
	1.5 GHz < f ≤ 3 GHz	< -155 dBc	
	carrier offset 30 MHz		
	3 GHz < f ≤ 6.0 GHz	< -155 dBc	
SSB phase noise	single-ended and differential sine wave of	r differential square wave: carrier offset	
ood pridde ridiod	20 kHz, measurement bandwidth 1 Hz	ameronial equal o mave, carner eneet	
	f = 10 MHz	< -163 dBc, -168 dBc (typ.)	
	f = 100 MHz	< -155 dBc, -161 dBc (typ.)	
	f = 1 GHz	< -135 dBc, -140 dBc (typ.)	
	f = 2 GHz	< -129 dBc, -134 dBc (typ.)	
	f = 3 GHz	< -125 dBc, -134 dBc (typ.)	
	f = 4 GHz	< -123 dBc, -130 dBc (typ.)	
	f = 6 GHz		
		< -119 dBc, -124 dBc (typ.)	
	instruments equipped with R&S®SMAB-B		
	f = 10 MHz	< -163 dBc, -168 dBc (typ.)	
	f = 100 MHz	< -158 dBc, -163 dBc (typ.)	
	f = 1 GHz	< -141 dBc, -145 dBc (typ.)	
	f = 2 GHz	< -135 dBc, -139 dBc (typ.)	
	f = 3 GHz	< -131 dBc, -135 dBc (typ.)	
	f = 4 GHz	< -129 dBc, -133 dBc (typ.)	
	f = 6 GHz	< -125 dBc, -129 dBc (typ.)	
RMS jitter	single-ended and differential sine wave o		
	f = 155 MHz, BW = 100 Hz to 1.5 MHz	18.3 fs (meas.)	
	f = 622  MHz, BW = 1  kHz to 5 MHz	18.0 fs (meas.)	
	f = 1 GHz, $BW = 1 Hz$ to $10 MHz$	558 fs (meas.)	
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	18.0 fs (meas.)	
With R&S <sup>®</sup> SMAB-B709 option	f = 155  MHz, BW = 100  Hz to  1.5  MHz	13.6 fs (meas.)	
	f = 622  MHz, BW = 1 kHz to 5 MHz	13.7 fs (meas.)	
	f = 1 GHz, $BW = 1 Hz$ to 10 $MHz$	129 fs (meas.)	
	f = 2.488  GHz, $BW = 5  kHz$ to 20 MHz	13.6 fs (meas.)	
With R&S®SMAB-B710(N) or	f = 155 MHz, BW = 100 Hz to 1.5 MHz	13.6 fs (meas.)	
R&S®SMAB-B711(N) option	f = 622 MHz, BW = 1 kHz to 5 MHz	13.7 fs (meas.)	
	f = 1 GHz, BW = 1 Hz to 10 MHz	21.6 fs (meas.)	
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	13.7 fs (meas.)	



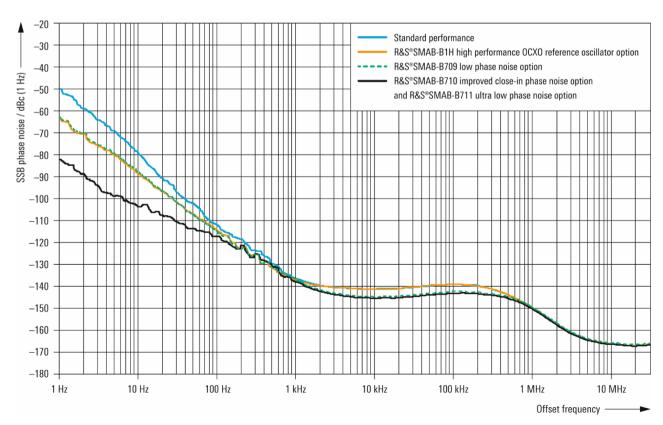
Measured wideband noise of clock synthesizer output at maximum output power versus carrier frequency with the R&S®SMAB-B29 and R&S®SMAB-K722 options; measured with the R&S®FSWP phase noise analyzer



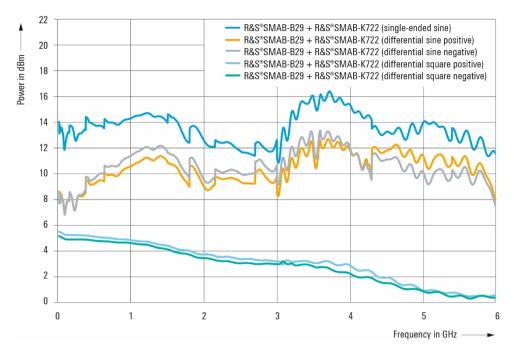
Measured SSB phase noise of clock synthesizer (standard performance) with the R&S®SMAB-B29 and R&S®SMAB-K722 options



Measured SSB phase noise of clock synthesizer with the R&S®SMAB-B29, R&S®SMAB-B711(N) and R&S®SMAB-K722 options



Measured SSB phase noise of clock synthesizer at f = 1 GHz, standard performance versus the R&S®SMAB-B1H, R&S®SMAB-B709, R&S®SMAB-B710(N) and R&S®SMAB-B711(N) options



Measured maximum available output power versus frequency for the R&S®SMAB-B29 and R&S®SMAB-K722 options

# R&S®NRP-Z power analysis (R&S®SMAB-K28 option)

### Overview of supported power sensor and functionalities

Latest power sensor firmware version is recommended.

Power sensor	Power vs. frequency and power vs. power	Power vs. time	Pulse data measurement
R&S®NRP-Z81/-Z85/-Z86	•	•	•

• = supported, - = not supported.

Modes		power vs. frequency     power vs. power
General settings		power vs. time (trace mode)
Number of points per sweep (= steps)		10 to 1000
Frequency range	depending on R&S®NRP-Zxx power sensor and R&S®SMA100B frequency option	full frequency range of signal generator or power sensor (whichever is lower); support of frequency-converting DUTs
Y-axis setting range		-200 dBm to +100 dBm
Uncertainty of measured power	determined by power sensor used and timing mode (noise)	see R&S®NRP-Zxx data sheet
Sweep mode		<ul><li>single</li><li>continuous</li></ul>
Number of traces	used for sensor data or as reference trace	4
Number of markers		4
Trace data export	supported file formats	JPG, BMP, XPM, PNG, CSV
Resolution of saved graphic file	for JPG, BMP, XPM and PNG file format	800 x 480 pixel (size of screen)
Power vs. frequency mode		
Spacing		linear, logarithmic
Timing mode		fast, normal
Sweep time	depends on timing mode, number of steps and power sensor	set automatically
	e.g. R&S®NRP-Z81 timing mode FAST, 200 steps	approx. 2.5 s
Power vs. power mode		1
Spacing		dB steps
Timing mode		fast, normal
Sweep time	depends on timing mode, steps and power sensor	set automatically
	e.g. R&S®NRP-Z81 timing mode FAST, 200 steps	approx. 2.5 s
Power vs. time mode (trace mode)		
Spacing		linear
Sweep time	R&S®NRP-Z81/-Z85/-Z86	
	setting range	100 ns to 1 s
	resolution (sweep time/steps ) ≥ 12.5 ns	12.5 ns
	resolution (sweep time/steps) < 12.5 ns, periodic signals, trigger mode internally triggered	2 ns
Trace offset	with reference to trigger event	positive, negative
Average	with reference to trigger event	1 to 1024
Trigger modes	internally triggered	auto, free run, internal
rnggermoues	externally triggered  R&S®NRP-Z3 required	external
Trigger level setting range	depends on power sensor used	see R&S®NRP-Zxx data sheet
Trigger hysteresis setting range	, , , , , , , , , , , , , , , , , , , ,	0 dB to 10 dB
Trigger dropout time setting range		0 ns to 10 s

### Version 04.00, December 2018

Available measurements in time m	ode	
Gate function		
Number of gates	user-selectable	2
Power measurements		peak power, average power
Pulse data measurement, only with R	R&S®NRP-Z81/-Z85/-Z86	
Timing measurements		duty cycle, pulse width, pulse period, pulse off time, rise time, pulse start time, overshoot, fall time, pulse stop time
Power measurements		peak power, average power, minimal power, top power, base power, distal power, mesial power, proximal power
Setting range for distal, mesial and proximal threshold	d voltage or power-related	0 % to 100 %

# **Remote control**

Interfaces/systems	standard	Ethernet/LAN 10/100/1000BASE-T
•	with R&S®SMAB-B86 option	IEC 60625 (GPIB IEEE-488.2),
		USB 2.0 (according to VISA USB-TMC),
		serial (RS-232) <sup>7</sup>
Command set	<del>-</del>	SCPI 1999.5 or compatible command sets
Compatible command sets	These command sets can be selected in	Hewlett Packard
	order to emulate another instrument.  A subset of common commands is	<ul><li>HP 8340, HP 8341</li><li>HP 8360</li></ul>
	supported.	<ul> <li>HP 83620, HP 83622, HP 83623,</li> </ul>
	For each emulated instrument, the *IDN?	HP 83624
	and *OPT? strings can be configured to	• HP 83630, HP 83640, HP 83650
	meet the specific requirements. This is	• HP 8373
	particularly useful for the	• HP 83711, HP 83712
	Aeroflex/IFR/Marconi instruments since	• HP 83731, HP 83732
	the manufacturer ID changed over time	• HP 8642, HP 8643, HP 8644, HP 8645
	and for the Hewlett-Packard/Agilent	• HP 8647, HP 8648
	instruments to adapt to a specific suffix	• HP 8656, HP 8657
	and configuration.	<ul> <li>HP 8662, HP 8663, HP 8664, HP 8665</li> <li>HP 8673</li> </ul>
		• HP 00/3
		Agilent/Keysight Technologies
		• E4421, E4422, E4428
		• E8257, E8663
		• N5161, N5181, N5183
		Aeroflex (IFR/Marconi)
		• 2023, 2024
		<ul><li>2030, 2031, 2032</li><li>2040, 2041, 2042</li></ul>
		2040, 2041, 2042
		Anritsu
		• 68017, 68037
		Panasonic
		• VP-8303A
		Racal Dana
		• 3102, 9087
		Rohde & Schwarz
		R&S®SMA100A
		• R&S®SME02/03/06
		R&S®SMF100A  R&S®SMF100A
		R&S®SMG/SMH      R&S®SMCH/SMHH
		<ul> <li>R&amp;S®SMGU/SMHU</li> <li>R&amp;S®SML01/02/03</li> </ul>
		<ul> <li>R&amp;S*SME01/02/03</li> <li>R&amp;S*SMP02/03/04</li> </ul>
		<ul> <li>R&amp;S*SMR20/27/30/40</li> </ul>
		• R&S®SMT02/03/06
		• R&S®SMY01/02
IEC/IEEE bus address		0 to 30
Ethernet/LAN protocols and services		VISA VXI-11 (remote control)
		Telnet/RawEthernet (remote control)      NAC (remote an area time with weathernet)
		VNC (remote operation with web     browser)
		<ul><li>browser)</li><li>FTP (file transfer protocol)</li></ul>
		SMB (mapping parts of the instrument)
		to a host file system)
Ethernet/LAN addressing		DHCP, static;
· ·		support of ZeroConf and M-DNS to
		facilitate direct connection to a system
		controller

<sup>&</sup>lt;sup>7</sup> Requires recommended extra R&S®TS-USB1.

### **Connectors**

All digital inputs and outputs are CMOS 3.3 V unless otherwise noted. The input damage level is -0.5 V/+5 V.

### Front or rear panel connectors

These connectors are located either on the front or the rear panel of the instrument, depending on the option configuration.

Instrument with 2 HU (equipped with the R&S $^{\circ}$ SMAB-B92 option): RF 50  $\Omega$ , USB, SENSOR, SD card on the front panel, all others on the rear panel.

Instrument with 3 HU (equipped with the R&S®SMAB-B93 option): all connectors on front panel.

Instrument with 2 or 3 HU and equipped with an R&S®SMAB-B80/-B81 rear panel connector option: all except USB on the rear panel.

RF 50 Ω	RF output		
	R&S®SMAB-B103, R&S®SMAB-B106	N female	
	R&S®SMAB-B112, R&S®SMAB-B120	test port adapter, PC 2.92 mm female	
		(interchangeable port connector system)	
LF	LF generator output	BNC female	
Ext 1, Ext 2	input for external analog modulation	BNC female	
	(AM, FM, φM, Scan AM)		
Input impedance		100 kΩ; 600 $\Omega$ or 50 $\Omega$ (nom.)	
Input sensitivity	AM, FM, φM: peak value for set deviation	1 V (nom.)	
Input voltage range	Scan AM		
	Ext 1	-6 V to 0 V	
	Ext 2	-1 V to 0 V	
Input damage voltage	50 Ω input impedance	±7 V	
	$600~\Omega$ and $100~k\Omega$ input impedance	±10 V	
Pulse Ext	input for external pulse modulation,	BNC female/digital signal	
	external trigger input for pulse generator,		
	external gate input for pulse generator		
Input impedance	selectable	10 kΩ or 50 Ω (nom.)	
Input voltage	TTL , CMOS compatible		
	threshold voltage	0 V to 2.0 V (nom.)	
Input damage voltage		-0.5 V/+5 V	
Input polarity	selectable	normal, inverse	
Pulse Video	pulse generator output,	BNC female/digital signal	
	video output for external pulse modulation		
Pulse Sync	synchronizing output for pulse generator	BNC female/digital signal	
SENSOR	connector for R&S®NRP power sensor	6 pol. ODU mini-snap series B	
USB	USB 2.0	USB type A	
	connector for external USB devices such		
	as mouse, keyboard, R&S®NRP power		
	sensors (with R&S®NRP-Z4 adapter		
	cable), memory stick for software update		
	and data exchange or USB serial adapter		
	for RS-232 remote control		
SD	with R&S®SMAB-B85 option	SD card slot	
	for removable mass storage		
Clk Sync	clock synthesizer output	SMA female	
Clk Sync_N	clock synthesizer inverted output	SMA female	

### **Rear panel connectors**

-		
Ref. In	external reference frequency input	BNC female
Input damage level		> 20 dBm
Ref. Out	reference frequency output	BNC female
Ref. In 1 GHz	external 1 GHz reference frequency input	SMA female
Input damage level		> 20 dBm
Ref. Out 1 GHz	ultra low noise 1 GHz reference frequency	SMA female
	output	
Ext. Tune	input for electronic tuning of internal	BNC female
	reference frequency	
Inst. Trig.	trigger input for sweep and list mode	BNC female/digital signal
Signal Valid	output for triggering external devices,	BNC female/digital signal
	low state indicates that the instrument has	
	settled to its final value	

V/GHz X-Axis	with R&S®SMAB-B28 option, delivers voltage level proportional to absolute sweep frequency or sweep progress	BNC female
Load impedance		≥ 1 kΩ
Z-Axis	with R&S®SMAB-B28 option, delivers pulses with different levels to indicate frequency markers and blanking signals	BNC female
Load impedance		≥ 10 kΩ
Stop	with R&S®SMAB-B28 option, bidirectional signal to indicate halted sweep or to stop sweep by external device	BNC female/digital signal
Input polarity		Low active
Marker User 1	with R&S®SMAB-B28 option, pulse output to mark selected frequencies	BNC female/digital signal
Input polarity	selectable	normal, inverse
LAN	provides remote control functionality and other services, see section "Remote control"	RJ-45
USB	USB 2.0 connector for external USB devices such as mouse, keyboard, R&S®NRP power sensors (with adapter cable R&S®NRP-Z4), memory stick for software update and data exchange or USB serial adapter for RS-232 remote control	USB type A
USB In	with R&S®SMAB-B86 option, USB 2.0, remote control of instrument	USB type micro-B
IEEE 488	with R&S®SMAB-B86 option, remote control of instrument via GPIB	24-pin Amphenol series 57 female

# General data

Power rating		
Rated voltage		100 V to 240 V AC (± 10 %)
Rated frequency		50 Hz to 60 Hz (± 5 %), 400 Hz (± 5 %)
Rated current	instrument with 2 HU	3.5 A to 1.6 A (50 Hz to 60 Hz),
	(R&S®SMAB-B92 option)	3.5 A to 2.9 A (400 Hz)
	instrument with 3 HU (R&S®SMAB-B93 option)	7.3 A to 4.6 A (50 Hz to 60 Hz/400 Hz)
Rated power	instrument with 2 HU (R&S®SMAB-B92 option), when fully equipped	300 W (meas.)
	instrument with 3 HU (R&S®SMAB-B93 option), when fully equipped	300 W (meas.)
Power factor correction  Product conformity	,	in line with EN 61000-3-2
Electromagnetic compatibility	EU: in line with EMC Directive 2004/108/EC	<ul> <li>applied harmonized standards:</li> <li>EN 61326-1 (industrial environment)</li> <li>EN 61326-2-1</li> <li>EN 55011 class A</li> <li>EN 61000-3-2</li> </ul>
Electrical safety	EU: in line with Low Voltage Directive	EN 61000-3-3     applied harmonized standard:
	2006/95/EC	EN 61010-1
	USA	UL 61010-1
	Canada	CAN/CSA-C22.2 No. 61010-1
International safety approvals	VDE – Association for Electrical, Electronic and Information Technologies	GS mark 40045930
	CSA – Canadian Standards Association	CSA <sub>UL</sub> mark 70108101
Mechanical resistance	CONTROL CLANGE OF THE CONTROL	oo ig man re roe is .
Vibration	sinusoidal	5 Hz to 55 Hz, 0.15 mm amplitude const.,
VIDIALIOII	Sinasoraal	55 Hz to 150 Hz, 0.5 g const., in line with EN 60068-2-6
	random	10 Hz to 300 Hz, acceleration 1.2 g RMS, in line with EN 60068-2-64
Shock		40 g shock spectrum, in line with MIL-STD-810E, method 516.4, procedure
Environmental conditions		, , , , , , , , , , , , , , , , , , , ,
Temperature range	operation	0 °C to +55 °C
Damp heat	storage	-40 °C to +71 °C +40 °C, 90 % rel. humidity, steady state, in line with EN 60068-2-78
Altitude	operating, linear derating of max. ambient temperature to +45 °C starting at altitude = 3000 m	4600 m (15000 ft)
	transport	4600 m (15000 ft)
Weight and dimensions		
Dimensions (L × W × H)	instrument with 2 HU	472 mm × 445 mm × 108 mm
	(R&S®SMAB-B92 option),	(18.58 in × 17.52 in × 4.25 in)
	without front handles and instrument feet,	428 mm × 425 mm × 88 mm
	for use with extra R&S®ZZA-xxx	(16.83 in × 16.73 in × 3.47 in)
	instrument with 3 HU	472 mm × 445 mm × 152 mm
	(R&S®SMAB-B93 option),	$(18.58 \text{ in} \times 17.52 \text{ in} \times 5.98 \text{ in})$
	without front handles and instrument feet,	428 mm × 425 mm × 133 mm
	for use with extra R&S <sup>®</sup> ZZA-xxx	(16.83 in × 16.73 in × 5.22 in)
Weight	2 HU instrument	14.4 kg (31.7 lb)
**Olgin	(R&S <sup>®</sup> SMAB-B92 option),	17.7 Ng (01.1 lb)
	. ,	
	when fully equipped	19.0 kg (41.9 lb)
	3 HU instrument	

Display		
Resolution		800 x 480 pixel
Size	2 HU instrument	5" touch display
	3 HU instrument	7" touch display
Calibration interval		
Recommended calibration interval	operation 40 h/week in the full range of the	3 years
	specified environmental conditions	

# **Ordering information**

R&S®SMAB-Bxxx = hardware option R&S®SMAB-Kxxx = software/keycode option

Designation	Туре	Order No.
Signal Generator <sup>8</sup>	R&S®SMA100B	1419.8888.02
including power cable and quick start guide		
Options		
Frequency options		
8 kHz to 3 GHz	R&S®SMAB-B103	1420.8488.02
8 kHz to 6 GHz	R&S®SMAB-B106	1420.8588.02
8 kHz to 12.75 GHz	R&S®SMAB-B112	1420.8688.02
8 kHz to 20 GHz	R&S®SMAB-B120	1420.8788.02
Platform height options		,
2 HU with 5" touch display	R&S®SMAB-B92	1420.8288.02
3 HU with 7" touch display	R&S®SMAB-B93	1420.8388.02
Phase noise performance and reference oscillator options		,
High performance OCXO reference oscillator 9	R&S®SMAB-B1H	1420.8188.02
Low phase noise 9	R&S®SMAB-B709	1420.9849.02
Improved close-in phase noise performance	R&S®SMAB-B710	1420.8007.02
for R&S <sup>®</sup> SMAB-B106/-B112/-B120 <sup>9</sup>	_	
Improved close-in phase noise performance	R&S®SMAB-B710N	1420.8107.02
for R&S®SMAB-B103 9		
Ultra low phase noise	R&S®SMAB-B711	1420.8020.02
for R&S <sup>®</sup> SMAB-B106/-B112/-B120 <sup>9</sup>		
Ultra low phase noise for R&S®SMAB-B103 9	R&S®SMAB-B711N	1420.8120.02
100 MHz, 1 GHz ultra low noise reference input/output	R&S®SMAB-K703	1420.9761.02
Flexible reference input from 1 MHz to 100 MHz	R&S®SMAB-K704	1420.9778.02
Output power options		
High output power 3 GHz/6 GHz	R&S®SMAB-K31	1420.7100.02
Ultra high output power 3 GHz/6 GHz <sup>10</sup>	R&S®SMAB-B32	1420.7200.02
High output power 12.75 GHz/20 GHz	R&S®SMAB-K33	1420.7300.02
Ultra high output power 12.75 GHz/20 GHz 11	R&S®SMAB-B34	1420.7400.02
Analog modulation options		
High performance pulse modulator	R&S®SMAB-K22	1420.9710.02
Pulse generator	R&S®SMAB-K23	1420.9726.02
Multifunction generator	R&S®SMAB-K24	1420.9732.02
VOR/ILS	R&S®SMAB-K25	1420.9855.02
Pulse train <sup>12</sup>	R&S®SMAB-K27	1420.9749.02
AM/FM/φM	R&S®SMAB-K720	1420.9790.02
Scan AM <sup>13</sup> <sup>14</sup>	R&S®SMAB-K721	1420.9784.02
Additional performance options	11100 011111211121	1 120101 0 1102
Ramp sweep	R&S®SMAB-B28	1420.6579.02
High dynamic uninterrupted level sweep 14	R&S®SMAB-K724	1420.9832.02
Differential clock synthesizer 3 GHz	R&S®SMAB-B29	1420.8088.02
Clock synthesizer frequency extension to 6 GHz (only for	R&S®SMAB-K722	1420.9810.02
instruments equipped with R&S®SMAB-B106/-B112/-B120)	1100 0 12 11. 22	
Power analysis	R&S®SMAB-K28	1420.9755.02
Other options	,	1
Rear panel connectors (3 GHz/6 GHz)	R&S®SMAB-B80	1420.6504.02
Rear panel connectors (12.75 GHz/20 GHz)	R&S®SMAB-B81	1420.6510.02
Removable mass storage	R&S®SMAB-B85	1420.6556.02
Remote control GPIB and USB	R&S®SMAB-B86	1420.6562.02

<sup>&</sup>lt;sup>8</sup> The base unit can only be ordered with an R&S®SMAB-B1xx frequency option and an R&S®SMAB-B92 or R&S®SMAB-B93 platform height option.

Only one of the following six options can be installed: R&S®SMAB-B1H, R&S®SMAB-B709, R&S®SMAB-B710, R&S®SMAB-B710N, R&S®SMAB-B711N.

 $<sup>^{10}\,</sup>$  R&S $^{\!0}$ SMAB-B32 can only be ordered with R&S $^{\!0}$ SMAB-K31.

 $<sup>^{11}\,</sup>$  R&S $^{\!0}$ SMAB-B34 can only be ordered with R&S $^{\!0}$ SMAB-K33.

<sup>&</sup>lt;sup>12</sup> Requires R&S<sup>®</sup>SMAB-K23 pulse generator option.

 $<sup>^{13}\,</sup>$  Requires R&S®SMAB-K720 AM/FM/ $\phi M$  option.

<sup>&</sup>lt;sup>14</sup> For instruments with serial number < 102000, please contact the Rohde & Schwarz service department.

Designation	Туре	Order No.
Recommended extras		
19" rack adapter for 2 HU model	R&S®ZZA-KNA21	1177.8026.00
19" rack adapter for 3 HU model	R&S®ZZA-KNA31	1177.8032.00
USB serial adapter for RS-232 remote control	R&S®TS-USB1	6124.2531.00
Spare SD card	R&S®SMAB-Z10	1420.6662.02
Adapters for instruments with an R&S®SMAB-B112/-B1	20 frequency option	
Test port adapter, 2.4 mm female		1088.1627.02
Test port adapter, 2.92 mm female		1036.4790.00
Test port adapter, 2.92 mm male		1036.4802.00
Test port adapter, N female		1036.4777.00
Test port adapter, N male		1036.4783.00
Documentation		
Documentation of calibration values	R&S®DCV-2	0240.2193.18
R&S®SMA100B accredited calibration	R&S®SMA100B-ACA	1420.6740.02

Warranty		
Base unit		3 years
All other items <sup>15</sup>		1 year
Options		
Extended warranty, one year	R&S®WE1	Please contact your local
Extended warranty, two years	R&S®WE2	Rohde & Schwarz sales office.
Extended warranty with calibration coverage, one year	R&S®CW1	
Extended warranty with calibration coverage, two years	R&S®CW2	
Extended warranty with accredited calibration coverage,	R&S®AW1	
one year		
Extended warranty with accredited calibration coverage,	R&S <sup>®</sup> AW2	
two years		

#### Extended warranty with a term of one and two years (WE1 and WE2)

Repairs carried out during the contract term are free of charge <sup>16</sup>. Necessary calibration and adjustments carried out during repairs are also covered.

#### Extended warranty with calibration coverage (CW1 and CW2)

Enhance your extended warranty by adding calibration coverage at a package price. This package ensures that your Rohde & Schwarz product is regularly calibrated, inspected and maintained during the term of the contract. It includes all repairs <sup>16</sup> and calibration at the recommended intervals as well as any calibration carried out during repairs or option upgrades.

#### Extended warranty with accredited calibration (AW1 and AW2)

Enhance your extended warranty by adding accredited calibration coverage at a package price. This package ensures that your Rohde & Schwarz product is regularly calibrated under accreditation, inspected and maintained during the term of the contract. It includes all repairs <sup>16</sup> and accredited calibration at the recommended intervals as well as any accredited calibration carried out during repairs or option upgrades.

<sup>15</sup> For options that are installed, the remaining base unit warranty applies if longer than 1 year. Exception: all batteries have a 1 year warranty.

<sup>&</sup>lt;sup>16</sup> Excluding defects caused by incorrect operation or handling and force majeure. Wear-and-tear parts are not included.

### Service that adds value

- Uncompromising qualityLong-term dependability

#### Rohde & Schwarz

The Rohde & Schwarz electronics group offers innovative solutions in the following business fields: test and measurement, broadcast and media, secure communications, cybersecurity, monitoring and network testing. Founded more than 80 years ago, the independent company which is headquartered in Munich, Germany, has an extensive sales and service network with locations in more than 70 countries.

www.rohde-schwarz.com

#### Sustainable product design

- Environmental compatibility and eco-footprint
- Energy efficiency and low emissions
- Longevity and optimized total cost of ownership

Certified Quality Management ISO 9001

Certified Environmental Management ISO 14001

#### Rohde & Schwarz training

www.training.rohde-schwarz.com

#### **Regional contact**

- Europe, Africa, Middle East | +49 89 4129 12345 customersupport@rohde-schwarz.com
- North America | 1 888 TEST RSA (1 888 837 87 72) customer.support@rsa.rohde-schwarz.com
- Latin America | +1 410 910 79 88 customersupport.la@rohde-schwarz.com
- Asia Pacific | +65 65 13 04 88 customersupport.asia@rohde-schwarz.com
- China | +86 800 810 82 28 | +86 400 650 58 96 customersupport.china@rohde-schwarz.com

